NSN 5961-01-023-2830

Transistor - Page 1 of 1

Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-023-2830 **Inclosure Material:** Metal **Overall Length:** 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.210 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -30.0 drain to gate voltage and -30.0 drain to source voltage and -30.0 reverse gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 200.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 23115-102377 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**